NSN 5961-01-023-5125

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-023-5125 **Inclosure Material:** Plastic **Overall Length:** 1.200 inches **Overall Height:** Between 0.170 inches and 0.190 inches Overall Width: Between 0.360 inches and 0.400 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-202 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -90.0 collector to emitter voltage, dc with base short-circuited to emitter and -75.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 6.25 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No